OCET 2011

Question Booklet Series : A

Important : <u>Please consult your Admit Card / Roll No. Slip before filling your Roll Number on the Test Booklet</u> and Answer Sheet.

Roll No.	In Figures	In Words
]
O.M.R. Ansv	wer Sheet Serial N	0.
	Si	nature of the Candidate :
Paper : I		
Subject : M	.Tech. (Instrume	ntation)
Time : 90 minu	tes N	mber of Questions : 75 Maximum Marks : 75
DO	NOT OPEN THE SE	L ON THE BOOKLET UNTIL ASKED TO DO SO

INSTRUCTIONS

- 1. Write your Roll No. on the Question Booklet and also on the OMR Answer Sheet in the space provided and nowhere else.
- 2. Enter the Subject and Series Code of Question Booklet on the OMR Answer Sheet. Darken the corresponding bubbles with **Black Ball Point / Black Gel pen.**
- 3. Do not make any identification mark on the Answer Sheet or Question Booklet.
- 4. To open the Question Booklet remove the paper seal (s) gently when asked to do so.
- 5. Please check that this Question Booklet contains **75** questions. In case of any discrepancy, inform the Assistant Superintendent within 10 minutes of the start of test.
- 6. Each question has four alternative answers (A, B, C, D) of which only one is correct. For each question, darken only one bubble (A or B or C or D), whichever you think is the correct answer, on the Answer Sheet with **Black Ball Point / Black Gel pen.**
- 7. If you do not want to answer a question, leave all the bubbles corresponding to that question blank in the Answer Sheet. No marks will be deducted in such cases.
- 8. Darken the bubbles in the OMR Answer Sheet according to the Serial No. of the questions given in the Question Booklet.
- 9. If you want to change an already marked answer, erase the shade in the darkened bubble completely.
- 10. Negative marking will be adopted for evaluation i.e., 1/4th of the marks of the question will be deducted for each wrong answer. A wrong answer means incorrect answer or wrong filling of bubble.
- 11. For calculations, use of simple log tables is permitted. Borrowing of log tables and any other material is not allowed.
- 12. For rough work only the sheets marked "Rough Work" at the end of the Question Booklet be used.
- 13. The Answer Sheet is designed for **computer evaluation**. Therefore, if you do not follow the instructions given on the Answer Sheet, it may make evaluation by the computer difficult. Any resultant loss to the candidate on the above account, i.e., not following the instructions completely, shall be of the candidate only.
- 14. After the test, hand over the Question Booklet and the Answer Sheet to the Assistant Superintendent on duty.
- 15. In no case the Answer Sheet, the Question Booklet, or its part or any material copied/noted from this Booklet is to be taken out of the examination hall. Any candidate found doing so, would be expelled from the examination.
- 16. A candidate who creates disturbance of any kind or changes his/her seat or is found in possession of any paper possibly of any assistance or found giving or receiving assistance or found using any other unfair means during the examination will be expelled from the examination by the Centre Superintendent/Observer whose decision shall be final.
- 17. Telecommunication equipment such as pager, cellular phone, wireless, scanner, etc., is not permitted inside the examination hall. Use of calculators is not allowed.

Sr. No. :

M.Tech. (Instrumentation)/A/OEC-22657

M.Tech. (Instrumentation)/A

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1.	What is maximum data capacity for optic	cal fiber ca	able ?	
	(A) 10 mbps	(B)	100 mbps	
	(C) 1000 mbps	(D)	10000 mbps	
2.	What is the central device in star topolog	y in comp	uter networking ?	
	(A) STP server	(B)	Hub/Switch	
	(C) PDC	(D)	Router	
3.	The number of digits in Hexadecimal sys	tem is :		
	(A) 15	(B)	17	
	(C) 16	(D)	8	
4.	For large networks topology is us	ed.		
	(A) Bus	(B)	Star	
	(C) Ring	(D)	Delta	
5.	ISO stands for :			
	(A) International Standard Organization	(B)	International Student Organization	
	(C) Integrated Services Organization	(D)	International Service Organization	
6.	Resistivity of silicon in ohms cm is approx	x. equal to	:	
	(A) 50 K	(B)	1012 ohm	
	(C) 230 K	(D)	10-6 ohm	
7.	A Kb corresponds to :			
	(A) 1024 bits	(B)	1000 bytes	
	(C) 1048 bytes	(D)	948 bits	
8.	The forbidden energy gap for silicon is :			
	(A) 1.1 eV	(B)	067 eV	
	(C) 0.97 eV	(D)	1.7 eV	
9.	Impurity atoms that produces N type ma	terial by it	s addition in semiconductor is called :	
	(A) Donor	(B)	Acceptor	
	(C) Conductor	(D)	Insulator	
10.	IC 8085 is a :			
	(A) Microcontroller	(B)	Microprocessor	
	(C) Micromemory	(D)	Arithmetic Logic Unit	
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11.	Point contact diodes are preferred at very	high frequency, because of its low junction :
	(A) Capacitance and inductance	(B) Inductance
	(C) Capacitance	(D) Mobility
12.	Another name for horizontal retrace in TV	receiver is the :
	(A) Ringing	(B) Burst
	(C) Damper	(D) Fly back
13.	Another name for the colour sync in the co	lour TV system :
	(A) Ringing	(B) Burst
	(C) Damper	(D) Fly back
14.	In a transistor if Alpha = 0.98, current gain	n is equal to :
	(A) 29	(B) 59
	(C) 69	(D) 49
15.	The active region in the common emitter c	onfiguration means :
	(A) Both collector and emitter junction is re-	verse biased
	(B) The collector junction is forward biased	and emitter junction
	(C) The collector junction is reverse biased a	and emitter junction is forward biased
	(D) Both collector and emitter junction are f	orward biased
16.	In an amplitude modulated signal, lower si	de band frequency is equal to if the carrier frequency is
	fc and modulation frequency is fm :	
	(A) $fm + fc$	(B) $fc - fm$
	(C) fm r fc	(D) fc/fm
17.	Modulation index of the frequency modula	tion depends on :
	(A) Amplitude and frequency of the modular	tion signal
	(B) Frequency and amplitude of carrier signa	al
	(C) Carrier frequency	
	(D) None of these	
18.	Reverse saturation current of a Ge diode is	s in the range of :
	(A) mA	(B) uA
	(C) nA	(D) pA
19.	Every 10°C rise in temperature the reverse	saturation current of diode :
	(A) Doubles	(B) Halves
	(C) Triples	(D) No change
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20.	A Metal or Semiconductor carrying a current field E is induced in :	I is pl	aced in a transverse magnetic field B, an electric
	(A) Parallel to B	(B)	Prependicular to I
	(C) Perpendicular to both B and I	(D)	Prependicular to B
21.	1 eV (electron volt) is equal to :		
	(A) $6.23 \times 10^{-20} \text{ J}$	(B)	$1.6 imes 10^{-19}~{ m J}$
	(C) $6.23 \times 10^{-18} \text{ J}$	(D)	$1.16\times10^{-19}J$
22.	Germanium has the valency of :		
	(A) 2	(B)	3
	(C) 4	(D)	5
23.	Hole acts as a free charge carrier of polarity	•	
	(A) Negative	(B)	Positive
	(C) Neutral	(D)	Depends on temperature
24.	Notch filter is :		
	(A) Low pass filter	(B)	High pass filter
	(C) Narrow stop band filter	(D)	Narrow pass band filter
25.	The characteristics of FET are similar to :		
	(A) Triode	(B)	Tertode
	(C) Pentode	(D)	Diode
26.	Charge coupled device is an array of capacito	ors wł	nose structure is similar to :
	(A) Shift register	(B)	Flip-flop
	(C) NAND gate	(D)	Amplifier
27.	Operational amplifier characteristics are whi	ich of	the following ?
	(A) Infinite gain		
	(B) Low input impedance		
	(C) Output impedance equal to output impedan	ice	
	(D) Inifinite output impedance		
28.	The important application of Schmitt trigger	is :	
	(A) To convert slowly varying input voltage to	abrup	t voltage change
	(B) To convert abruptly varying input voltage i	nto slo	owly varying output
	(C) To change the frequency of the input		
	(D) None of these		

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29 .	Meaning of decoding is :		
	(A) Binary addition	(B) Data transmission	
	(C) Demultiplexing	(D) Storage of binary information	
30 .	The important use of low pass filter in powe	er supply is :	
	(A) To get the regulation in the output voltage	(B) To filter out the ripple frequency	
	(C) To increase the current rating	(D) To convert AC into DC	
31.	Binary equivalent of the decimal number 14	5 is :	
	(A) 10010001	(B) 1001011	
	(C) 1010001	(D) 1100010	
32.	In which of the following gate the output wi	ll be high when all the inputs are at high le	evel?
	(A) NOR	(B) AND	
	(C) NAND	(D) EXOR	
33.	Four bit code is called :		
	(A) Nibble	(B) Byte	
	(C) Word	(D) Register	
34.	Analog signal varies with :		
	(A) sampling time	(B) time continuously	
	(C) sampling frequency	(D) none of these	
35.	In amplitude modulation, frequency is :		
	(A) constant	(B) zero	
	(C) variable	(D) one	
36.	The frequency range of 1 GHZ to 30 GHZ a	re referred as :	
	(A) sound waves	(B) micro waves	
	(C) mini waves	(D) UV waves	
37.	Low pass filter attenuates :		
	(A) high frequencies	(B) low frequencies	
	(C) medium frequencies	(D) low and medium frequencies	
38.	Micro wave communication is used in :		
	(A) ISDN	(B) Mobile telephone networks	
	(C) Industries computer networking	(D) Fiber optic telephones	
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39 .	Optical detector is :		
	(A) Light emitting diode	(B)	PIN photo diode
	(C) BJT	(D)	MOSFET
40 .	Optical fibre is fabricated with :		
	(A) glass	(B)	copper
	(C) aluminium	(D)	rubber
41 .	Primary colours are :		
	(A) red, blue, green	(B)	green, white, blue
	(C) blue, red, yellow	(D)	green, magenta, cyan
42 .	Respiratory volume is measured using :		
	(A) Myograph	(B)	Pneumograph
	(C) Spiro meter	(D)	Goniometer
43.	Piezo-electric materials have resistivity	y.	
	(A) Zero	(B)	Infinite
	(C) Finite	(D)	Null
44.	One of the combination of materials used for o	optic	al fibers are
	(A) Copper core and glass cladding	(B)	Glass core and aluminium cladding
	(C) Glass core and plastic cladding	(D)	Plastic core and glass cladding
45.	An anavational amplification of		
	An operational amplifier is a :		
	S1 : Direct coupled high gain amplifier		
	S1 : Direct coupled high gain amplifier S2 : Device to perform linear operation		
	 An operational amplifier is a : S1 : Direct coupled high gain amplifier S2 : Device to perform linear operation (A) S1 is true and S2 is false 	(B)	S2 is true and S1 is false
	 An operational amplifier is a : S1 : Direct coupled high gain amplifier S2 : Device to perform linear operation (A) S1 is true and S2 is false (C) Both S1 and S2 are true 	(B) (D)	S2 is true and S1 is false Both S1 and S2 are false
46.	 An operational amplifier is a : S1 : Direct coupled high gain amplifier S2 : Device to perform linear operation (A) S1 is true and S2 is false (C) Both S1 and S2 are true Power supply rejection ratio of an OPAMP shows 	(B) (D) ould	S2 is true and S1 is false Both S1 and S2 are false be :
46.	 An operational amplifier is a : S1 : Direct coupled high gain amplifier S2 : Device to perform linear operation (A) S1 is true and S2 is false (C) Both S1 and S2 are true Power supply rejection ratio of an OPAMP sho (A) Ideally unity 	(B) (D) ould (B)	S2 is true and S1 is false Both S1 and S2 are false be : Zero
46.	 An operational amplifier is a : S1 : Direct coupled high gain amplifier S2 : Device to perform linear operation (A) S1 is true and S2 is false (C) Both S1 and S2 are true Power supply rejection ratio of an OPAMP she (A) Ideally unity (C) As small as possible 	(B) (D) ould (B) (D)	S2 is true and S1 is false Both S1 and S2 are false be : Zero As large as possible
46. 47.	 An operational amplifier is a : S1 : Direct coupled high gain amplifier S2 : Device to perform linear operation (A) S1 is true and S2 is false (C) Both S1 and S2 are true Power supply rejection ratio of an OPAMP sho (A) Ideally unity (C) As small as possible The ideal value of CMRR is : 	(B) (D) ould (B) (D)	S2 is true and S1 is false Both S1 and S2 are false be : Zero As large as possible
46. 47.	 An operational amplifier is a : S1 : Direct coupled high gain amplifier S2 : Device to perform linear operation (A) S1 is true and S2 is false (C) Both S1 and S2 are true Power supply rejection ratio of an OPAMP sh (A) Ideally unity (C) As small as possible The ideal value of CMRR is : (A) 1 	(B) (D) ould (B) (D) (B)	S2 is true and S1 is false Both S1 and S2 are false be : Zero As large as possible
46. 47.	 An operational amplifier is a : S1 : Direct coupled high gain amplifier S2 : Device to perform linear operation (A) S1 is true and S2 is false (C) Both S1 and S2 are true Power supply rejection ratio of an OPAMP sh (A) Ideally unity (C) As small as possible The ideal value of CMRR is : (A) 1 (C) -∞ 	(B) (D) ould (B) (D) (B) (D)	S2 is true and S1 is false Both S1 and S2 are false be : Zero As large as possible 0 ∞

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48.	DC amplifiers are generally :	
	S1 : Negative feedback type	
	S2 : Positive feedback type	
	(A) S1 is true and S2 is false	(B) S2 is true and S1 is false
	(C) Both S1 and S2 are true	(D) Both S1 and S2 are false
49 .	MRI makes use of the region of the ele	ectromagnetic spectra to provide an image.
	(A) Ultra Violet Frequency	(B) Radio Frequency
	(C) Infra Red Frequency	(D) Ultra High Frequency
50 .	Ultrasound is a form of energy which consists	of :
	S1 : Mechanical vibrations of high frequency	
	S2 : Electrical vibrations of high frequency	
	(A) S1 is true	(B) S2 is true
	(C) S1 and S2 are true	(D) S1 and S2 are false
51.	The use of super conducting magnets in MRI	is to obtain :
	(A) Signals from surface tissue	(B) High RF field
	(C) High strength gradient fields	(D) High strength magnetic fields
52.	A current carrying coil is subjected to a uniform	m magnetic field. The coil will orient so that its plane
	becomes :	
	(A) inclined at 45° to the magnetic field	
	(B) inclined at any arbitrary angle to the magnet	tic field
	(C) parallel to the magnetic field	
	(D) perpendicular to magnetic field	
53.	Tesla is the unit of :	
	(A) magnetic flux	(B) magnetic field
	(C) magnetic induction	(D) magnetic moment
54.	The total charge induced in a conducting loop	moving in magnetic field depends upon :
	(A) the rate of change of magnetic flux	(B) initial magnetic flux only
	(C) the total change in magnetic flux	(D) final magnetic flux only
55.	A uniform magnetic field acts right angles to electron moves in a circular path of radius 2 cm of the circular path will be :	the direction of motion of electrons. As a result, the n. If the speed of electrons is doubled, then the radius

(A)	2.0 cm	(B)	0.5 cm
(C)	4.0 cm	(D)	1.0 cm

(1)

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56.	To convert a galvanometer into an ammeter,	, one needs to connect a :	
	(A) low resistance in parallel	(B) high resistance in parallel	
	(C) low resistance in series	(D) high resistance in series	
57.	When a proton is accelerated through I V, th	en its kinetic energy will be :	
	(A) 930 eV	(B) 13.6 eV	
	(C) 1 eV	(D) 0.54 eV	
58.	If a diamagnetic substance is brought near n	orth or south pole of a bar magnet, it is :	
	(A) attracted by the poles		
	(B) repelled by the poles		
	(C) repelled by north pole and attracted by the	e south pole	
	(D) attracted by the north pole and repelled by	the south pole	
59 .	There are Bravais Lattices of Crystal	ıl.	
	(A) 4	(B) 7	
	(C) 14	(D) 16	
60 .	The conductivity of a semiconductor crystal	due to any current carrier is not proportional to :	
	(A) mobility of the carrier	(B) effective density of states in the conduction bar	nd
	(C) electronic charge	(D) surface states in the semiconductor	
61 .	An SSi Chip has logic gates on it.		
	(A) less than 4	(B) less than 12	
	(C) more than 12 but less than 100	(D) less than 1000 but more than 100	
62 .	Which one of the following is an essential con	mponents of electromechanical relays ?	
	(A) Graphite rod	(B) SCR	
	(C) Electromagnet	(D) MOSFET	
63.	Which of the following is a non-polar dielect	tric ?	
	(A) Polystyrene	(B) Phenolic plastics	
	(C) Plasticized cellulose acetate	(D) Castor oil	
64.	The impurity in liquid dielectric which has s	significant effect in reducing the breakdown strengt	t h,
	is :		
	(A) dust	(B) dissolved gases	
	(C) moisture	(D) ionic impurities	
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65.	Van de Graaff generators are useful	for :		
	(A) Very high voltage and low current applications			
	(B) Very high voltage and high current applications			
	(C) Constant high voltage and current	applications		
	(D) High voltage pulses only			
66.	Switching surge is :			
	(A) high voltage dc	(B)	high voltage ac	
	(C) short duration transient voltage	(D)	hyperbolically dying voltage	
67.	In 'plasma' state a gas :			
	(A) loses electrical conductivity	(B)	conducts electricity	
	(C) becomes perfect insulator	(D)	attracts moisture	
68.	Fleming's left hand rule may be appl	ied to an elect	ric generator to find out :	
	(A) direction of rotor rotation	(B)	polarity of induced emf	
	(C) direction of induced emf	(D)	direction of magnetic field	
69 .	A language in which a statement in a	loop that runs	s 100 times and is decoded 100 times, is :	
	(A) BASIC	(B)	FORTRAN	
	(C) COBOL	(D)	PASCAL	
70 .	Which of the following is not a high l	evel computer	programming language ?	
	(A) FORTRAN	(B)	MODEM	
	(C) COBOL	(D)	ALGOL	
71 .	The symbol shown in the figure in flo	w chart repre	sents :	
	(A) Input	(B)	Output	
	(C) Decision	(D)	Termination	
72.	The voltage levels for a Zero logic in	a digital system	m :	
	(A) must necessarily be negative	(B)	could be negative or positive	
	(C) must necessarily be positive	(D)	must necessarily be either zero or -5 V	
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73. Which logic circuit is the fastest ?

- (A) TTL(B) DTL(C) RTL(D) All have same speed
- 74. Which of the following sets represents a universal logic family ?
 - (A) NAND (B) XOR
 - (C) NAD (D) None of the above

75. The maximum propagation value in case of 7400 NAND gates is :

(A) 1 second

(B) 20 milli seconds

(C) less than 20 nano seconds

(D) less than 20 pico seconds

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